Triacs logic level

BT137S-600D

## **GENERAL DESCRIPTION**

# Passivated, sensitive gate triac in a plastic envelope, suitable for surface mounting, intended for use in general purpose bidirectional switching and phase control applications. This device is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

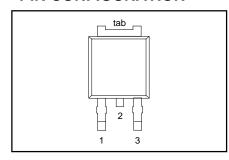
## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	MAX.	UNIT
V <sub>DRM</sub>	Repetitive peak off-state voltage	600	V
I <sub>T(RMS)</sub>	RMS on-state current	8	A
I <sub>TSM</sub>	Non-repetitive peak on-state current	65	A

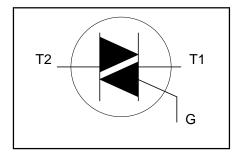
## **PINNING - SOT428**

PIN	DESCRIPTION		
1	MT1		
2	MT2		
3	gate		
tab	MT2		

# **PIN CONFIGURATION**



# **SYMBOL**



## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>DRM</sub>	Repetitive peak off-state voltage		-	600 <sup>1</sup>	V
I <sub>T(RMS)</sub>	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 102 ^{\circ}\text{C}$ full sine wave; $T_{j} = 25 ^{\circ}\text{C}$ prior to surge	-	8	А
	on state surront	t = 20 ms	-	65	A
12,	121 6 - 1 - 1 - 1	t = 16.7 ms	-	71	A A <sup>2</sup> s
l²t dl <sub>⊤</sub> /dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after	I = 10  ms $I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $I_{G} = 0.2 \text{ A}$	-	21	A-S
	triggering	T2+ G+	-	50	A/μs
		T2+ G-	-	50	A/μs
		T2- G-	-	50	A/μs
1.	Dook goto ourrent	T2- G+	-	10	A/μs
$oldsymbol{V}_GM$	Peak gate current Peak gate voltage		-	5	I A
P <sub>GM</sub>	Peak gate power		-	5	١ẅ́
P <sub>G(AV)</sub>	Average gate power	over any 20 ms period	_	0.5	l w
T <sub>sta</sub>	Storage temperature	ary 20 me pened	-40	150	l∵ċ
T <sub>stg</sub>	Operating junction temperature		-	125	°C

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<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/µs.

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# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction to mounting base	full cycle half cycle	-	-	2.0 2.4	K/W K/W
R <sub>th j-a</sub>	Thermal resistance junction to ambient	pcb (FR4) mounted; footprint as in Fig.14	-	75	-	K/W

## STATIC CHARACTERISTICS

T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>GT</sub>	Gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}$				
		T2+ G		2.5	5	mΑ
		T2+ G	·   -	3.5	5	mΑ
		T2- G-	-	3.5	5	mΑ
		T2- G-	.   -	6.5	10	mΑ
I <sub>1</sub>	Latching current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$				
		T2+ G	+   -	1.6	15	mΑ
		T2+ G	.   -	8.5	20	mΑ
		T2- G-	-	1.2	15	mΑ
		T2- G-	.   -	2.5	20	mΑ
l <sub>H</sub>	Holding current	$V_D = 12 \text{ V}; I_{GT} = 0.1 \text{ A}$	-	1.5	10	mΑ
ĺΫ́τ	On-state voltage	$I_{T} = 10 \text{ A}$	-	1.3	1.65	V
$\left  egin{array}{c} oldsymbol{I_H} \ oldsymbol{V_T} \ oldsymbol{V_{GT}} \end{array} \right $	Gate trigger voltage	$\dot{V}_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$	-	0.7	1.5	V
		$V_D = 400 \text{ V}; I_T = 0.1 \text{ A}; T_L = 125 ^{\circ}\text{C}$	0.25	0.4	-	V
I <sub>D</sub>	Off-state leakage current	$V_D = V_{DRM(max)}$ ; $T_j = 125$ °C	-	0.1	0.5	mA

# **DYNAMIC CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; $R_{GK} = 1 k\Omega$		5	-	V/μs
t <sub>gt</sub>	Gate controlled turn-on time	$I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

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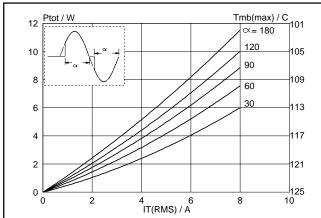


Fig.1. Maximum on-state dissipation,  $P_{tot}$ , versus rms on-state current,  $I_{T(RMS)}$ , where  $\alpha =$  conduction angle.

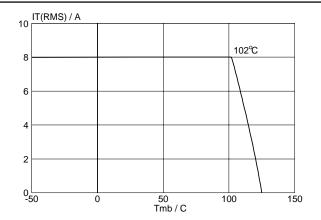


Fig.4. Maximum permissible rms current  $I_{T(RMS)}$ , versus mounting base temperature  $T_{mb}$ .

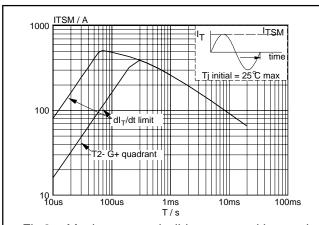


Fig.2. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_p \le 20$ ms.

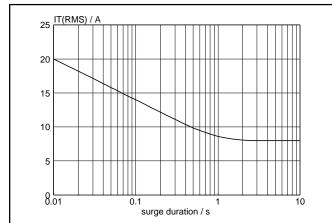


Fig.5. Maximum permissible repetitive rms on-state current  $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz;  $T_{mb} \le 102$  °C.

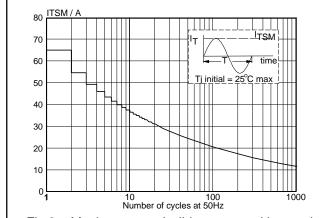


Fig.3. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus number of cycles, for sinusoidal currents, f = 50 Hz.

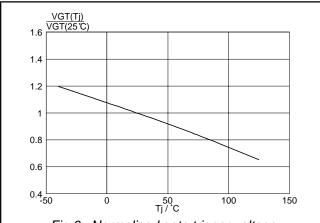
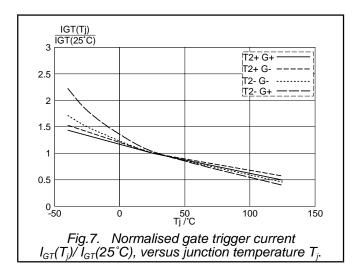
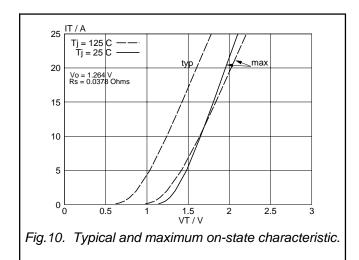


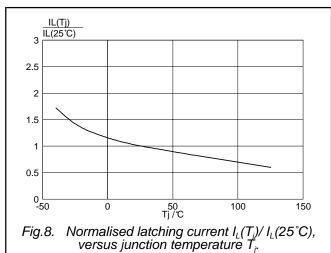
Fig.6. Normalised gate trigger voltage  $V_{GT}(T_j)/V_{GT}(25^{\circ}C)$ , versus junction temperature  $T_j$ .

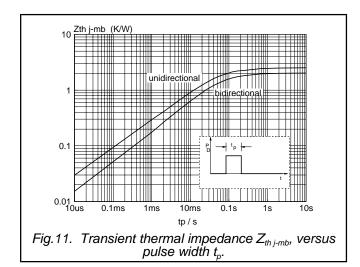
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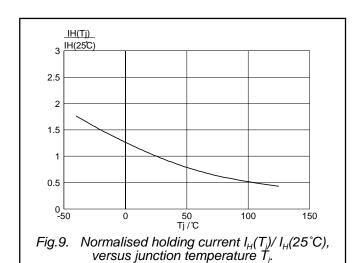
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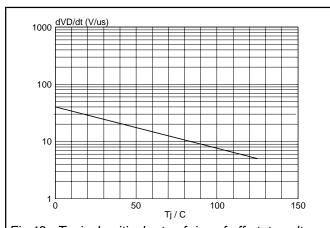


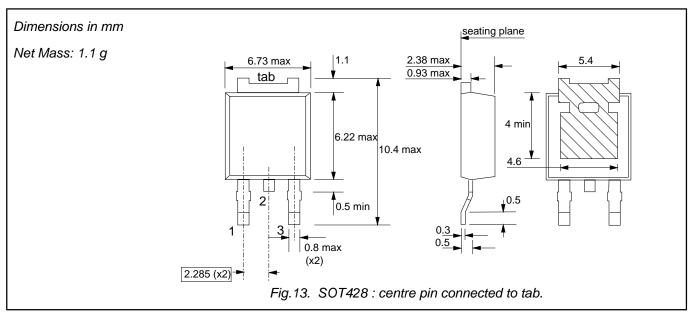
Fig.12. Typical, critical rate of rise of off-state voltage, dV<sub>D</sub>/dt versus junction temperature T<sub>j</sub>.

Philips Semiconductors Product specification

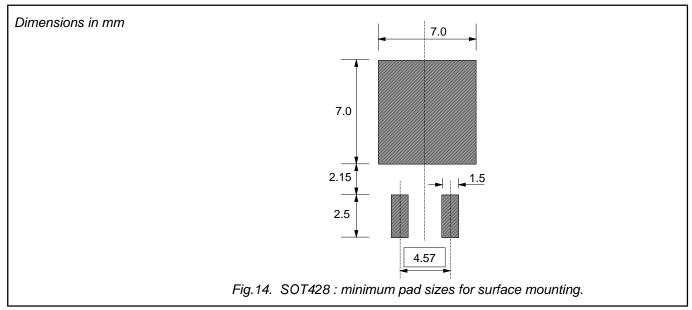
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# **MECHANICAL DATA**



# **MOUNTING INSTRUCTIONS**



## **Notes**

1. Plastic meets UL94 V0 at 1/8".

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## **DEFINITIONS**

DATA SHEET STATUS				
DATA SHEET STATUS <sup>2</sup>	PRODUCT STATUS <sup>3</sup>	DEFINITIONS		
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice		
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in ordere to improve the design and supply the best possible product		
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A		

#### Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

# **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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